

COMMON PRE-BOARD EXAMINATION 2022-23

Subject: PHYSICS (042)



Class: XII

Date:

Time: 3 Hours

Max. Marks: 70

General Instructions:

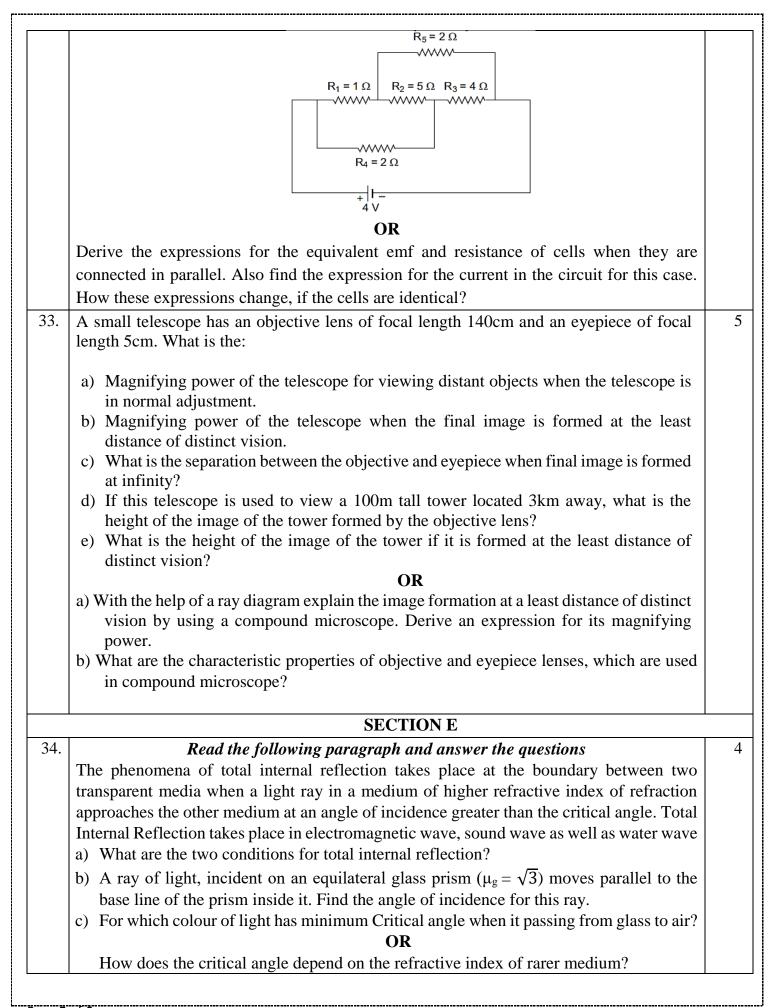
- 1. There are 35 questions in all. All questions are compulsory
- 2. This question paper has five sections: Section A, Section B, Section C, Section D and Section E. All the sections are compulsory.
- 3. Section A contains eighteen MCQ of 1 mark each, Section B contains seven questions of two marks each, Section C contains five questions of three marks each, section D contains three long questions of five marks each and Section E contains two case study-based questions of 4 marks each.
- **4.** There is no overall choice. However, an internal choice has been provided in section B, C, D and E. You have to attempt only one of the choices in such questions.
- 5. Use of calculators is not allowed.

	SECTION A	
1.	If $\oint \vec{E} \cdot d\vec{S} = 0$ over a surface, then	1
	(a) the electric field inside the surface and on it is zero.	
	(b) the electric field inside the surface is necessarily uniform.	
	(c) the number of flux lines entering the surface must be equal to the number of flux lines	
	leaving it.	
	(d) all charges must necessarily be inside	
2.	Two identical capacitors of 12 pF each are connected in series across a 50 V battery. Calculate	1
	the electrostatic energy stored in the combination.	
	(a) $7.5 \times 10^{-9} \text{J}$ (b) $3.0 \times 10^{-8} \text{J}$ (c) $5.6 \times 10^{-7} \text{J}$ (d) $9.4 \times 10^{-6} \text{J}$	
3.	Some charge is being given to a conductor. Then, its potential	1
	(a) is maximum at surface.	
	(b) is maximum at centre.	
	(c) is maximum somewhere between surface and centre.	
	(d) remains the same throughout the conductor.	
4.	Which one of the following characteristics of electrons determine the current in a conductor?	1
	(a) Drift velocity	
	(b) Thermal velocity	
	(c) Both drift velocity and thermal velocity	
	(d) Neither drift nor thermal velocity	
5.	An electron is projected with uniform velocity along the axis of a current carrying long	1
	solenoid. Which of the following is true?	
	(a) The electron will be accelerated along the axis	
	(b) The electron path will be circular about the axis	
	(c) The electron will experience a force at 45° to the axis and hence execute a helical path	
	(d) The electron will continue to move with uniform velocity along the axis of the solenoid	

6.	A voltmeter of range 2V and resistance 300 Ω cannot be converted to an ammeter of range:	1
0.	(a) 5 mA (b) 8 mA (c) 1 A (d) 10 A	1
7.	The self-inductance L of a solenoid of length <i>l</i> and area of cross-section A, with a fixed number	1
'.	of turns N increases as	1
	(a) <i>l</i> and A increase. (b) <i>l</i> decreases and A increases.	
	(c) <i>l</i> increases and A decreases. (d) both <i>l</i> and A decrease.	
8.	A magnet is dropped with its north pole towards a closed circular coil placed on a table then	1
0.	(a) looking from above, the induced current in the coil will be anti-clockwise.	1
	(b) the magnet will fall with uniform acceleration.	
	(c) looking from above, the induced current in the coil will be clockwise.	
	(d) no current will be induced in the coil.	
9.	An inductor of reactance 1 Ω and a resistor of resistance 2 Ω are connected in series to the	1
).	terminals of a 6 V ac source. The power dissipated in the circuit is	1
	(a) 8 W (b) 12 W (c) 14.4 W (d) 18 W	
10.	To reduce the resonant frequency in an LCR series circuit with a generator	1
10.	(a) the generator frequency should be reduced.	1
	(b) another capacitor should be added in parallel to the first.	
	(c) the iron core of the inductor should be removed.	
	(d) dielectric in the capacitor should be removed.	
11.	The electric field intensity produced by the radiations coming from 100 W bulb at a 3 m	1
11.	distance is E. The electric field intensity produced by the radiations coming from 50 W bulb	1
	at the same distance is	
	ν/2	
12.	In a Young's double-slit experiment the fringe width is found to be 0.4 mm. If the whole	1
	apparatus is dipped in water of refractive index 4/3, without disturbing the arrangement, the	
	new fringe width will be	
	(a) 0.2 mm (b) 0.40 mm (c) 0.53 mm (d) 0.30 mm	
13.	A proton, a neutron, an electron and an α-particle have same energy. Then the relation between	1
	de-Broglie wavelengths of these particles is	
	(a) $\lambda_P = \lambda_n > \lambda_e > \lambda_\alpha$ (b) $\lambda_\alpha < \lambda_p = \lambda_n > \lambda_e$	
	(c) $\lambda_e < \lambda_p = \lambda_n > \lambda_\alpha$ (d) $\lambda_e = \lambda_p = \lambda_n = \lambda_\alpha$	
14.	If an electron in a hydrogen atom jumps from the 3rd orbit to the 2nd orbit, it emits a photon	1
	of wavelength λ. When it jumps from the 4th orbit to the 3rd orbit, the corresponding	
	wavelength of the photon will be	
	$(a)^{\frac{16}{25}}\lambda$ $(b)^{\frac{9}{16}}\lambda$ $(c)^{\frac{20}{7}}\lambda$ $(d)^{\frac{20}{13}}\lambda$	
15.	The radius of a nucleus is	1
13.	(a) inversely proportional to the cube root of its atomic weight	1
	(b) inversely proportional to the cube root of its mass number	
	(c) directly proportional to the cube root of its mass number	
	(d) directly proportional to the cube root of its atomic weight	
	/w/ w 1 . L . L L	

For	question numbers 13 to 17, two statements are given- one labelled Assertion (A) and the other	ar
	lled Reason(R). Select the correct answer to these questions from the codes (a), (b), (c) and (
	iven below:	u)
	Both A and R are true and R is the correct explanation of A.	
` '	Both A and R are true but R is not the correct explanation of A.	
	A is true but R is false.	
	A is false but R is true.	
16.	Assertion: Diffraction takes place for all types of waves such as mechanical or non-	1
	mechanical, transverse or longitudinal.	
	Reason: Diffraction's effect are perceptible only if wavelength of wave is comparable to	
	dimensions of diffracting device.	
17.	Assertion: Two photons of equal wavelength must have equal linear momentum.	1
	Reason: Two photons of equal linear momentum will have equal wavelength	
18.	Assertion: Silicon is preferred over germanium for making semiconductor devices.	1
	Reason: The energy gap in germanium is more than the energy gap in silicon.	
	SECTION B	
19.	Two identical charges, Q each kept at a distance r from each other. A third charge q is	2
	placed on the line joining the above two charges such that all the three charges are in	
	equilibrium. What is the magnitude and the position of charge q	
20.	The susceptibility of a magnetic material is -2.6×10^{-5} . Identify the type of magnetic	2
	material and write its three properties.	
21.	The oscillating electric field of an electromagnetic wave is given by:	2
	$E_y = 30 \sin [2 \times 10^{11} t + 300 \pi x] V/m$	
	a) Obtain the value of the wavelength of the electromagnetic wave.	
	b) Write down the expression for the oscillating magnetic field.	
	OR	
22	How a microwave oven works to heat up a food item containing water molecules.	
22.	How does focal length of a lens change when red light incident on it is replaced by violet	2
	light? Give reason for your answer.	
23.	Find the ratio of intensities of two points P and Q on a screen of Young's double slit	2
	experiment, when waves from sources S_1 and S_2 have	
	a) phase difference of $\frac{\pi}{3}$ and $\frac{\pi}{2}$	
24	b) path difference of 0 and $\lambda/4$	
24.	³ He ₂ and ³ He ₁ nuclei have the same mass number. Do they have the same binding energy?	2
25	Why?	
25.	How can a diode act as a rectifier?	2
26	SECTION C	
26.	A Galvanometer of resistance G is converted into a voltmeter to measure upto V volts by	3
	connecting a resistance R_1 in series with the coil. If a resistance R_2 is connected in series	
	with it, then it can measure upto $V/2$ volts. Find the resistance, in terms of R_1 and R_2 ,	
	required to be connected to convert it into a voltmeter that can read upto 2V. Also find the	
	resistance G of the galvanometer in terms of R_1 and R_2 .	
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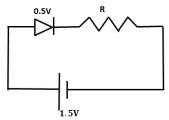
27		
27.	Derive an expression for the mutual inductance of two long co-axial solenoids. Write any	3
	two factors on which mutual inductance of solenoids depend.	
28.	Define rms value of alternating voltage and find its expression in terms of current	3
	amplitude.	
	OR	
	In a series LCR circuit with an ac source of effective voltage 50 V, frequency $v = 50 / \pi$	
	Hz, $R = 300\Omega$, $C = 20 \mu F$ and $L = 1.0 H$. Find the rms current in the circuit.	
29.	Light of wavelength 2000 Å falls on a metal surface of work functions 4.2 eV. What is the	3
	kinetic energy in eV of the fastest electrons emitted from the surface? What will be the	
	change in the energy of the emitted electrons if the intensity of light with same wavelength is doubled? If the same light falls on another surface of work functions 6.5 eV, what will	
	be the energy of emitted electrons?	
	OR	
	Draw a graph between the frequency of incident radiation and the maximum kinetic energy	
	of the electrons emitted from the surface of a photosensitive material. State clearly how	
	this graph can be used to determine (i) planks constant and (ii) work function of the	
20	material Silver Color of the Co	
30.	When the maximum kinetic energy of photo electrons double while the wavelength of light	3
	changes from λ_1 to λ_2 then find the expression threshold wavelength and work function	
	SECTION D	
31.	a. Two isolated metal sphere A and B have radii R and 2R respectively and same charge	5
	q. Find which of the two spheres have greater energy density just outside the surface	
	of the sphere.	
	1	
	b. Three identical capacitors C_1 , C_2 and C_3 of capacitance 6 μ F each one is connected to	
	b. Three identical capacitors C ₁ , C ₂ and C ₃ of capacitance 6 μF each one is connected to a 12 V battery as shown. Find: (i) charge on each capacitor (ii) equivalent capacitance	
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22	a 12 V battery as shown. Find: (i) charge on each capacitor (ii) equivalent capacitance of the network (iii) energy stored in the network of capacitors C1 T- C2 OR With the help of a diagram derive an expression for torque acting on a electric dipole when it is kept in the external electric field. What is the direction of this torque. Deduce the expression of the potential energy stored in the dipole.	
32.	a 12 V battery as shown. Find: (i) charge on each capacitor (ii) equivalent capacitance of the network (iii) energy stored in the network of capacitors C1 T- OR With the help of a diagram derive an expression for torque acting on a electric dipole when it is kept in the external electric field. What is the direction of this torque. Deduce the expression of the potential energy stored in the dipole. a) Calculate the emf and internal resistance of the equivalent cell, if two cells of emfs	4
32.	a 12 V battery as shown. Find: (i) charge on each capacitor (ii) equivalent capacitance of the network (iii) energy stored in the network of capacitors OR With the help of a diagram derive an expression for torque acting on a electric dipole when it is kept in the external electric field. What is the direction of this torque. Deduce the expression of the potential energy stored in the dipole. a) Calculate the emf and internal resistance of the equivalent cell, if two cells of emfs 1.5 V and 2 V having internal resistances 0.2 Ω and 0.3 Ω respectively are	
32.	a 12 V battery as shown. Find: (i) charge on each capacitor (ii) equivalent capacitance of the network (iii) energy stored in the network of capacitors C1 T- OR With the help of a diagram derive an expression for torque acting on a electric dipole when it is kept in the external electric field. What is the direction of this torque. Deduce the expression of the potential energy stored in the dipole. a) Calculate the emf and internal resistance of the equivalent cell, if two cells of emfs	5.



Read the following paragraph and answer the questions

Consider a thin p-type silicon semiconductor wafer. By adding precisely, a small quantity of pentavalent impurity, part of the p-Si wafer can be converted into n-Si. There are several processes by which a semiconductor can be formed. The wafer now contains p-region and n-region and a metallurgical junction between p and n-region. Two important processes occur during the formation of a p-n junction: diffusion and drift. We know that in an n-type semiconductor, the concentration of electrons is more compared to the concentration of holes. Similarly, in a p-type semiconductor, the concentration of holes is more than the concentration of electrons. During the formation of p-n junction, and due to the concentration gradient across p and n sides, holes diffuse from p-side to n-side and electrons diffuse from n-side to p-side. This motion of charge carriers gives rise to diffusion current across the junction.

- a) What is the effect of doping on width of depletion layer?
- b) A p-n junction diode when forward biased has a drop of 0.5 V which is assumed to be independent of current. The current in excess of 10 mA through the diode produces a large Joule heating which damages the diode. if we want to use a 1.5 V battery to forward bias the diode, what should be the value of resistor used in series with the diode so that the maximum current does not exceed 5mA?



c) Draw the energy band diagram for P type and N type semiconductor

OR

Draw the V-I graph in case of forward biasing and reverse biasing
